NSN 5961-01-380-1103

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-380-1103 **Inclosure Material:** Plastic **Overall Length:** Between 2.185 inches and 2.210 inches **Overall Height:** Between 0.240 inches and 0.280 inches Overall Width: Between 0.980 inches and 1.020 inches **End Application:** Aircraft, airlifter c-17a; aircraft, f-16 **Mounting Facility Quantity:** 2 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Mo-079ab **Component Name And Quantity:** 4 transistor **Mounting Method:** Unthreaded hole **Features Provided:** Electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 500.0 drain to gate voltage all transistor and 500.0 breakdown voltage, collector-to-emitter, base open all transistor **Current Rating Per Characteristic:** 41.00 amperes drain current all transistor **Power Rating Per Characteristic:** 400.0 watts total device dissipation all transistor **Test Data Document:** 07187-8509112 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 12 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

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